

# NV4V31MF

Blue-Violet Laser Diode 405 nm Blue-Violet Laser Light Source

## DESCRIPTION

The NV4V31MF is a blue-violet laser diode with a wavelength of 405 nm. A newly developed LD chip structure achieves a high optical power output of 175 mW (CW) at up to 85°C. The NV4V31MF can provide excellent linearity from low to high output at high temperatures, and reduces the unevenness of beam divergence.

## **FEATURES**

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- High optical output power
- $P_0 = 175 \text{ mW} @CW$  $\lambda_p = 405 \text{ nm TYP}.$
- Peak emission wavelength Single transverse mode (lateral)
- Wide operating temperature range •
- $\phi$  3.8 mm small CAN package

## **APPLICATIONS**

- Blue-violet laser light source •
- $T_C = -5$  to  $+85^{\circ}C$

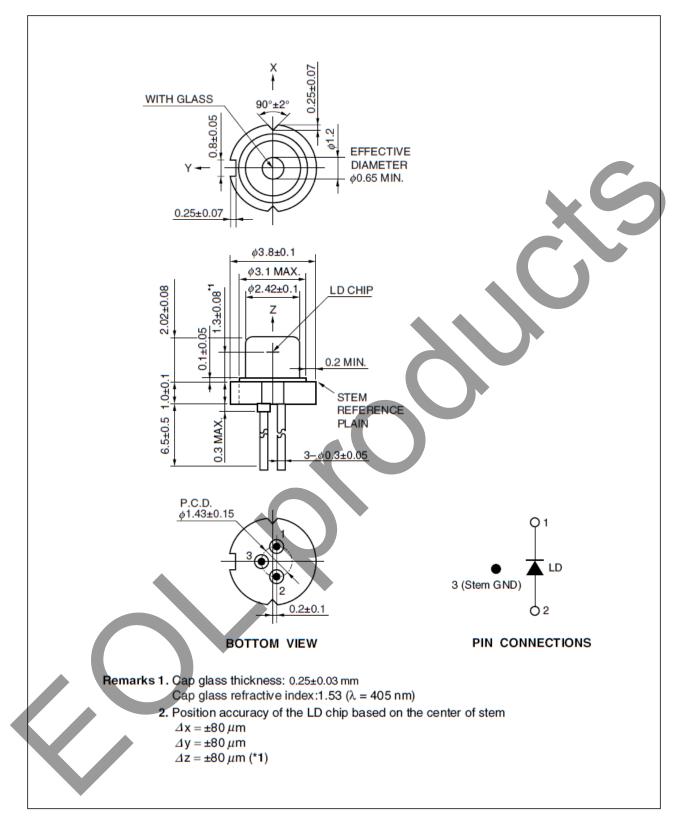
The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.



R08DS0045EJ0300 Rev.3.00 Aug 28, 2020

Page 1 of 7

### PACKAGE DIMENSIONS (UNIT: mm)



#### <R> ORDERING INFORMATION

Part Number	Order Number	Rank	Packing Style
NV4V31MF	NV4V31MF-A	GV	Tray Packing (250 p/Tray), Without data
	NV4V31MF-SA-A	KV	Individual Packing (for samples), Without data

## ABSOLUTE MAXIMUM RATINGS (T<sub>c</sub> = 25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Optical Output Power (CW)	Po	180	mW
Reverse Voltage of LD	VR	2	V
Operating Case Temperature	Tc	–5 to +85	°C
Storage Temperature	T <sub>stg</sub>	-40 to +85	°C

#### **RECOMMENDED OPERATING CONDITIONS** (Tc = 25°C, unless otherwise specified)

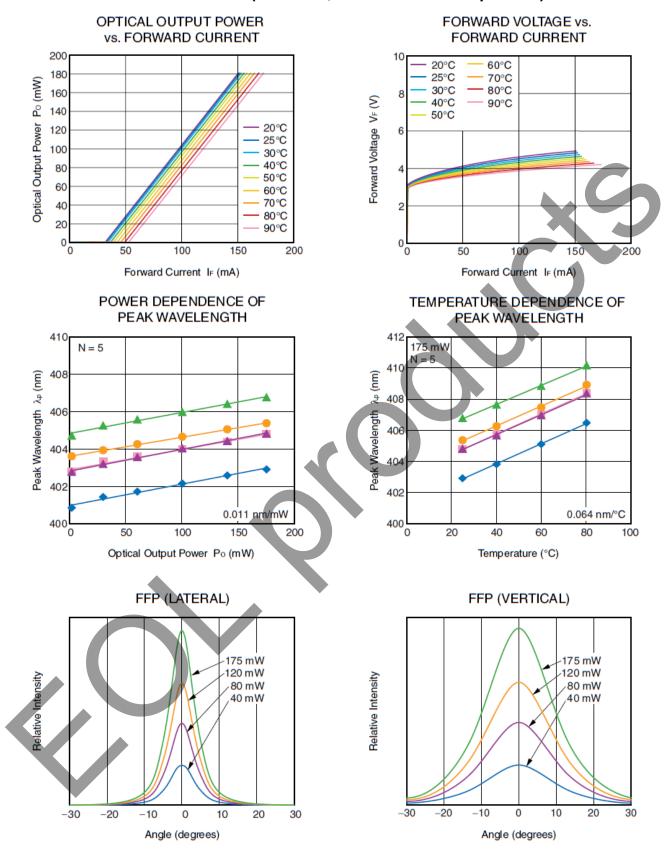
Parameter	Symbol	MAX.	Unit
Optical Output Power (CW)	Po	175	mW

## ELECTRO-OPTICAL CHARACTERISTICS (T<sub>c</sub> = 25°C, unless otherwise specified)

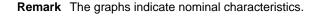
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Threshold Current	Ith	CW		35	55	mA
Operating Current	l <sub>op</sub>	CW, P <sub>o</sub> = 175 mW		150	200	mA
Optical Voltage	Vop	CW, P <sub>o</sub> = 175 mW		5.0	6.5	V
Slope Efficiency	$\eta_{d}$	CW, $P_0 = 20 \text{ mW}$ , 175 mW	1.1	1.55		W/A
Peak Wavelength	λρ	CW, P₀ = 175 mW	400	405	415	nm
Beam Divergence (lateral)	θ#	CW, P₀ = 175 mW	6	9	12	deg.
Beam Divergence (vertical)	$ heta_{\!\!\perp}$		15	20	25	
Position Accuracy Angle (lateral)	$\Delta \theta_{ll}$	CW, P <sub>o</sub> = 175 mW	-3	0	3	deg.
Position Accuracy Angle (vertical)	$\Delta  heta_{\!\!\perp}$		-3	0	3	

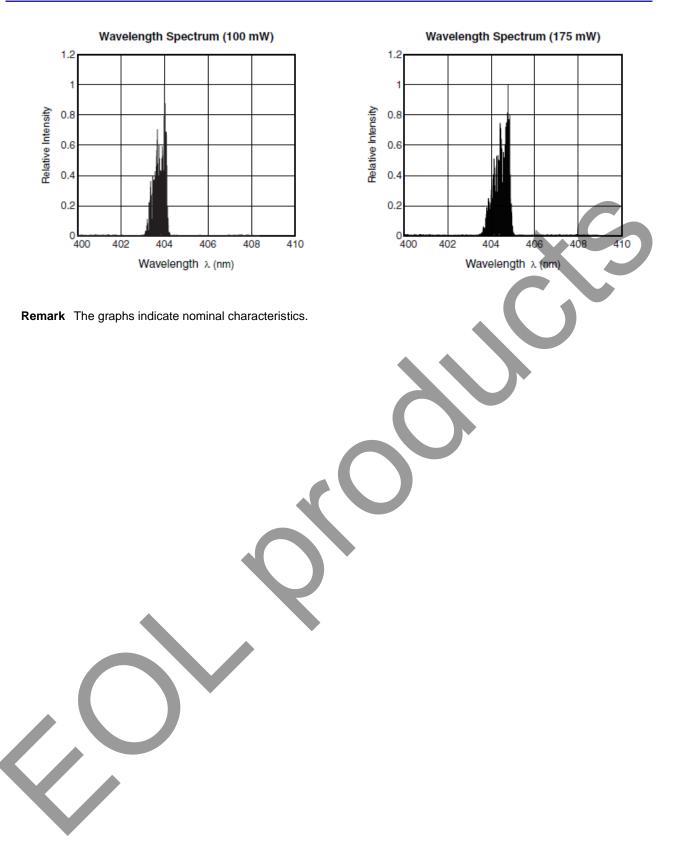






#### TYPICAL CHARACTERISTICS (Tc = 25°C, unless otherwise specified)







#### NOTES ON HANDLING

1. Recommended soldering conditions

- Peak Temperature  $\leq 350^{\circ}$ C
- Time  $\leq 3$  seconds
- Soldering of leads should be made at the point 2.0 mm from the root of the lead
- This device cannot be mounted using reflow soldering.
- 2. Usage cautions

(1) Take the following steps to ensure that the device is not damaged by static electricity.

- Wear an antistatic wrist strap when soldering the device.
  - We recommend a strap with a 1 M $\Omega$  resistor.
- Make sure that the work table and soldering iron are grounded.
- Make sure that the soldering iron does not leak.

(2) Do not subject the package to undue stress.

The package has a tensile strength of 1N or less. Do not exceed this rating. Also, avoid bending the leads as much as possible. If the leads must be bent, bend them only once, making sure to anchor the stem base of the lead

- (3) Do not allow the cap glass of the package to become scratched or dirty. Also, do not subject the cap glass to external force.
- (4) Be sure to attach a heat sink to sufficiently dissipate heat.
- (5) Use the device as soon as possible after opening the bag.



#### SAFETY INFORMATION ON THIS PRODUCT



#### SEMICONDUCTOR LASER

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AVOID EXPOSURE-Invisible Laser Radiation is emitted from this aperture

Warning Laser Beam	A laser beam is emitted from this diode during operation. If the laser beam or its reflection enters your eye, it may cause injury to the eye or loss of eyesight.
	(Note that, depending on the wavelength of the beam, the laser beam might not be visible.)
	Do not look directly into the laser beam.
	Avoid exposure to the laser beam, any reflected or collimated beam.

R08DS0045EJ0300 Rev.3.00 Aug 28, 2020

**Revision History** 

## NV4V31MF Data Sheet

		Description		
Rev.	Date	Page	Summary	
0.01	Sep 08, 2011	-	First edition issued	
1.00	Mar 05, 2012	Throughout	Preliminary Data Sheet -> Data Sheet	
		p.3	Modification of ORDERING INFORMATION	
		p.4, 5	Addition of TYPICAL CHARACTERISTICS	
2.00	Jun 20, 2013	p.1	Modification of FEATURES	
		p.2	Modification of PACKAGE DIMENSIONS	
		p.3	Modification of ORDERING INFORMATION	
			Modification of ABSOLUTE MAXIMUM RATINGS	
		p.4	Modification of TYPICAL CHARACTERISTICS	
		p.6	Modification of NOTES ON HANDLING	
		p.7	Modification of SAFETY INFORMATION ON THIS PRODUCT	
3.00	Aug 28,2020	p.3	Modification of ORDERING INFORMATION	
			(Newly established NV4V31MF-SA-A)	